Nanosized TiO\textsubscript{2} - Based Mixed Oxide Films: Sol-gel Synthesis, Structure, Electrochemical Characteristics and Photocatalytic Activity

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Abstract
A variety of mixed oxide nanostructured films (mesoporous TiO\textsubscript{2}/ZnO and TiO\textsubscript{2}/ZrO\textsubscript{2}, nonporous SiO\textsubscript{2}/TiO\textsubscript{2}/ZrO\textsubscript{2}) was synthesized by sol-gel method on the glass, titanium and silicon substrates using metal alkoxides (tetraethoxysilane, titanium tetraisopropoxide and zirconium tetrapropoxide) or (Zn (Ac)\textsubscript{2}) as precursors and Pluronic P123 as a template agent for mesoporous structure formation. TiO\textsubscript{2} films alone and TiO\textsubscript{2}/oxide composites were characterized using hexane adsorption, XRD, XPS, Raman and UV/vis spectroscopy. Band gap energy and the position of flatband potentials were estimated by photoelectrochemical measurements. On the base of analysis of the detail XPS spectra it was found the formation of Ti – O – Zn, Ti – O – Zr, Si – O – Ti, Si – O – Zr, Si – O – Ti – O – Zr bonds. Detected by XPS oxygen and silicon peak positions evolution correlated with \( E_g \) reduction of analyzed ternary mixed oxides and with the photocatalytic behavior of the films as well. An enhancement of photocatalytic activity of zirconia-doped films in comparison with that of pure TiO\textsubscript{2} originated from an anodic shift of the valence band edge potential. Catalytic activity of mesoporous TiO\textsubscript{2}/ZnO and TiO\textsubscript{2}/ZrO\textsubscript{2} films in the process of Cr\textsuperscript{VI} to Cr\textsuperscript{III} photoreduction was improved with increasing of surface acidity and specific surface area of the samples.

Keywords
Nanosized TiO\textsubscript{2} – Based Mixed Oxide Films, Structure, Photocatalysis

1. Introduction
Widespread use of a semiconductor photocatalysts for environmentally important processes of neutralization of toxic organic compounds and heavy metals in the waste water, drinking water and air caused by the need to create new nanomaterials based on titanium dioxide with high surface area, define structure, extended to the visible spectral range. It is known that TiO\textsubscript{2} effectiveness could be improved by mixing with other oxides that control structure-sorption, optical and electronic properties\textsuperscript{[1-5]}. Coupling of two semiconductors\textsuperscript{[6, 7]} is useful to achieve a more efficient separation of photogenerated electron-hole pair that led to improvement of the photoactivity. Also, it is found that the photocatalytic activity depends on the phase composition and crystalline size that modify the TiO\textsubscript{2} band gap\textsuperscript{[8-10]}. The size effect on the phase stability of nanostructures manifested in the stabilization of new phases, which is not characteristic to a bulk crystal, in some cases – amorphous\textsuperscript{[11]}. Authors\textsuperscript{[12, 13]} found out that the transformation sequence and thermodynamic phase stability depended on the initial particle sizes. For instance, rutile is most stable crystalline phase of TiO\textsubscript{2} in bulk, when anatase is thermodynamically stable in nanosized materials.

Sol-gel technology is one of the most practically useful techniques to prepare nanostructured complex oxide mixtures with atomic level mixing of the components. Generalized method for the synthesis of transition-metal oxides with high surface areas using the block copolymers as structure-directing agents was reported by\textsuperscript{[14]} and used for thin film of titanium dioxide formation\textsuperscript{[15]}. In our previous work, this approach has been extended to produce mixed oxide nanocomposites. Recently, we studied sol-gel TiO\textsubscript{2} films doped with transition metal ions, zirconium and zinc oxides in respect to their structural, optical and photocatalytic properties\textsuperscript{[16-21]}. Depending on the component ratios and conditions of thermal treatment the sol-gel method allows to obtain: 1) the products of replacement of the titanium ions in TiO\textsubscript{2} crystal lattice by transition metal ions\textsuperscript{[17]}; 2) solid solutions (Ti\textsubscript{1-x}Zr\textsubscript{x}O\textsubscript{2})\textsuperscript{[18, 19]} or 3) spinel phases – ZnTiO\textsubscript{3}, Zn\textsubscript{2}TiO\textsubscript{4}\textsuperscript{[20-22]}, Ti\textsubscript{2}ZrO\textsubscript{4}\textsuperscript{[23, 24]} and Fe\textsubscript{2}Ti\textsubscript{3}O\textsubscript{7}\textsuperscript{[25]}. The aim of the present paper is to discuss the phase composition, electronic
structure, electrochemical characteristics and their effect on the photocatalytic activity of sol-gel obtained mixed oxide films based on TiO₂.

2. Experimental

2.1. Synthesis of Materials

All reagents (Aldrich, reagent grade) were used as received. Template sol-gel method was applied for preparation of mesoporous TiO₂/ZnO, TiO₂/ZrO₂ and nonporous TiO₂/ZrO₂/SiO₂ ternary films at glass, silicon and aluminum substrates. Such alkoxides as tetraethoxysilane (TEOS), titanium tetraisopropoxide (TTIP) and zirconium tetrapropoxide (ZTP) were mixed with a water-ethanol solution for pre-hydrolysis. 1 M HNO₃ solution was used to adjust pH value on hydrolysis of TEOS. Hydrolysis of TTIP and ZTP is very fast in the presence of water resulting in the formation of precipitated. To prevent fast precipitation of titanium and zirconium hydroxides acetylacetone (acac) as a complexing agent was added to the solution. Ethanol solution of a template agent (nonionic triblock-copolymer of propyleneoxide with ethyleneoxide EO₂₀PO₇₀EO₂₀, Pluronic P123) was added to the solution of alkoxides after their pre-hydrolysis for 4-16 h to form ordered mesopores in the films. For TiO₂/ZnO films preparation zinc acetate (Aldrich) was used as metal source. The molar ratios of the components were as follow Ti(i-Pro)₄: Zn(CH₃COO)₂ : P123 : acetylacetone : H₂O : C₅H₂OH : HNO₃ as 1 : 0.01 : 0.05 : 0.5 : 1 : 40 : 1. The final molar ratio of components for the synthesis of TiO₂/ZrO₂ mesoporous films was Ti(OPr)₄ : Zr(OPr)₄ : P123 : acac : HNO₃ : H₂O : C₅H₂OH = 1 – 0.7 : 0 – 0.3 : 0.05 : 0.5 : 0.016 : 10 : 41. Precursor of nonporous ternary TiO₂/ZrO₂/SiO₂ film was prepared by addition of TTIP and ZTP (TiO₂/ZrO₂=0.7:0.3) acetylacetone solutions to prehydrolysed TEOS to adjust TiO₂/ZrO₂/SiO₂=21:9:70 or 49:21:30 composition.

For film deposition onto glass, silicon wafer or titanium substrates, dip-coating technique was utilized. After deposition of the film, gelation and gel ripening, it was dried in air at room temperature for 2 h (dried samples). Then the dried films were sintered in a furnace at a heating rate β = 2 K/min to 523 K, and at β = 0.25 K/min from 523 to 623 K. P123 burns out at these temperatures and this process should be carefully carried out for keeping the ordered porous structure of the oxide film. Then temperature was elevated to 773 at β = 3 K/min and the systems were kept at a certain temperature for 3 h.

To facilitate structural investigations by XRD and Raman spectroscopy powders with the same chemical composition have been prepared via gelation of the films’ precursors, their drying in air with following heat treatment according to the scheme described for the films

2.2. Characterization Techniques

XRD analysis of crystalline phases was performed using a DRON-4-07 (Burevestnik, St. Petersburg) diffractometer (Cu K₀α radiation with Ni filter) with Brag-Brentano registration geometry (2θ = 10–60°). The average size of crystallites was determined using Scherrer equation applied to the most intensive peak. The degree of the powders crystallinity was estimated as the ratio of integrated intensities, such as for the (101) line of the studied and reference standard samples (reference standard: TiO₂, anatase 100%).

The Raman spectra were detected by an automated double spectrometer DFS-24 (LOMO, Russia), followed by a cooled photomultiplier and registration system working in a photon counting mode. In connection to numerical analysis the spectra were digitalized in wide frequency range with a fixed increment (from 1 cm⁻¹ up to 5 cm⁻¹). For obtaining more reliable information, additional noise minimization technique was applied. In particular, relatively wide spectral windows of ~ 3.5 cm⁻¹, long acquisition time and optimized digital averaging of the spectra with a variable spectral window were used for weak signal amplification. The spectra were excited by radiation of Ar-ion laser (at λL=514.5 nm).

The electronic structure of the sol-gel film surface was explored by X-ray photoelectron spectroscopy (XPS) by electron spectrometer (E MgKα =1253.6 eV, P = 10⁻⁷ Pa) with PHOIBOS-100 energy analyzer SPECS (USA). The XPS peak decomposition was carried out by Gauss–Newton method, the area of peaks was determined after subtraction of background by Shirley method.

The photoelectrochemical properties of the TiO₂/ZnO and TiO₂/ZrO₂ electrodes were estimated using the spectral dependence of the photoelectrochemical current (iₚₑ), measured with a commercial spectrometer KSVU-1 (LOMO, Russia) with spectral resolution 1 nm. The experiments were carried out at 22°C under pure argon bubbling in the temperature-controlled quartz cell. The iₚₑ spectra were measured with usage of the mechanical light chopper of 20 Hz frequencies and standard circuit synchronous detection. A high-pressure xenon lamp with stabilized discharge current was used as light source. The iₚₑ spectra were expressed in units of quantum efficiency (electron/photon).

The resistance of TiO₂/ZrO₂ films on Ti substrate was measured by means of common alternating current bridge BM401. Ag/AgCl electrode was used as the reference electrode on the pH value of the electrolyte.

Photocatalytic activity of synthesized films has been checked in the process of Cr(VI) to Cr(III) photoreduction in water solution of K₂Cr₂O₇ (C₀=2·10⁻³ M) in the presence of EDTA (Cₐ=2·10⁻⁴ M) at pH = 2[26]. The open reactor with the reaction components (enabled continues inflow of oxygen) was irradiated with an UV light of mercury lamp PRK- 1000 with P₀ = 3 ·10⁻⁷ einstein dm⁻³ s⁻¹ intensity. Running water was circulated through the jacket to ensure constant temperature of the magnetically stirred reaction mixture. During the experiments concentration of reagents has been controlled with an UV-VIS spectrometer Perkin-Elmer Lambda-35. Half time of conversion Cr(VI) to Cr(III) in 20 ml of 2·10⁻⁴ M water solution of K₂Cr₂O₇ in the
presence of EDTA \((2\cdot10^{-4} \text{ M})\) at pH=2 over 1 film \((m=0.001\text{g})\).

3. Results and Discussion

3.1. Phase Composition and Electronic Structure of \(\text{TiO}_2/\text{ZnO}\) Films

The entire As we reported previously[21] hexane adsorption-desorption isotherms of the 500\degree C calcined \(\text{TiO}_2/\text{ZnO}\) films indicated mesoporosity[27] with hysteresis loop, which suggested bimodal porous size distribution with main pore sizes at \(r\sim 4\) and 8-10 nm. The specific surface area \((\text{SBET} \sim 300 \text{ m}^2/\text{g})\) was yielded from BET analysis of the isotherms for all \(\text{TiO}_2\) and \(\text{TiO}_2/\text{ZnO}\) samples. Freshly prepared \(\text{TiO}_2\) and \(\text{TiO}_2/\text{ZnO}\) films on glass showed highly hydrophilic properties, their water contact angles being ca. 5–7. Films with low Zn content (< 5%) differed significantly from pure \(\text{TiO}_2\) films and showed super-hydrophilicity with a water contact angle near 0.

![Figure 1](image1)

**Figure 1.** (a) X-Ray diffraction patterns of \(\text{TiO}_2/\text{ZnO}\) (1%) film; and (b) powders \(\text{TiO}_2\) (1), \(\text{TiO}_2/5\) atom % \(\text{ZnO}\) (2) and \(\text{TiO}_2/10\) atom % \(\text{ZnO}\) (3) calcined at 773K. * labels peaks for the new phase \(\text{ZnTiO}_3\), R - rutile

The crystalline structures of \(\text{TiO}_2/\text{ZnO}\) nanocomposites with dopant contents in the range 1–10 atom % were studied by XRD measurements of powders prepared from the precursor (Figure 1). The XRD patterns of \(\text{TiO}_2\) and \(\text{TiO}_2/1\) atom % \(\text{ZnO}\) only exhibited diffraction lines which were attributable to the crystalline anatase phase. When the dopant content was increased (up to 5 atom % \(\text{ZnO}\)), a very weak diffraction line assigned to the crystalline rutile phase of \(\text{TiO}_2\) was observed, while new peaks characteristic of the \(\text{ZnTiO}_3\) perowskite phase appeared in the XRD pattern for the \(\text{TiO}_2/10\) atom % \(\text{ZnO}\) sample. The initial crystallinity of the titania films (60%) slightly increased as the Zn content of the films increased. The average size of the anatase crystallites estimated via the Scherrer equation increased from 13 nm for \(\text{TiO}_2\) to 15–17 nm for the \(\text{TiO}_2/\text{ZnO}\) powders.

![Figure 2](image2)

**Figure 2.** (a) X-ray analysed EDS spectra of \(\text{Zn}^{2+}/\text{TiO}_2\) films and (b) Raman spectra of \(\text{Zn}^{2+}/\text{TiO}_2\) film (1), and Si wafer (2)

EDS EDS analysis of \(\text{Zn}^{2+}/\text{TiO}_2\) films using X-ray detector testified that zinc ions are present rather in the bulk (Fig. 2, a) than on the surface of film.

In terms of Raman spectroscopy, a well-resolved Raman peak at 145 cm\(^{-1}\) attributed to the main \(E_g\) anatase vibration mode and vibration peaks at 397 (\(B_{1g}\)) and 638 cm\(^{-1}\) (\(E_g\)) are detected in the spectrum of \(\text{Zn}^{2+}/\text{TiO}_2\) film. It was
reported[28] that the Raman band shift towards higher wavenumber and their maximum widening coincide with the titania particle size decrease.

Chemical state of elements and relationship between the matrix structures on the surface of films are investigated by XPS[20]. Nonsymmetrical Ti (2p) peaks registered in the spectra of all samples were deconvoluted (Fig 3, a) as the sum of 458.9 and 458.5 eV peaks corresponded to Ti-O-Ti and Ti-O-Zn bonds. In the region of Zn2p3/2 signal the peak (Fig. 3, b) attributed[29] to the formation of Ti-O-Zn (E_{BE}=1022.5 eV) and Zn-O-Zn bonds (E_{BE}=1021.7 eV) were registered.

![Graph A](image1.png)

**Figure 3.** XPS spectra of Zn2p – a, and Ti2p - b levels for Zn2+/TiO2 deconvoluted into components
The O1s spectra (not shown here) were separated into two main contributions that were assigned to the “$O^{2-}$” anions of the crystalline network (near 530.0 eV) and integrated as $-OH$ (532.5 eV) and adsorbed $H_2O$ (533.0 eV). The first peak is slightly shifted to lower $E_B$ value for the TiO$_2$/ZnO due to Ti–O–Zn bonds formation. As we reported previously [21] the total surface acid site density (B-centres + L-centres) according to Tanabe model[30] increased with zinc content.

### 3.2. Photoelectrochemical Characteristics and Photocatalytic Properties of TiO$_2$/ZnO Films

The position of the flatband potential ($U_{fb}$) of titania and TiO$_2$/ZnO films coated on the titanium substrates were estimated from photocurrent ($i_{ph}$) plotted against applied potential by extrapolation straight line of these dependences to the abscissa[31]. The enhancement of photocurrent generation efficiency indicate that Zn$^{2+}$ ions addition is beneficial to promote charge separation within nanostructured TiO$_2$ film and improve interfacial charge transfer process. Flatband potential values for the mesoporous TiO$_2$ and TiO$_2$/ZnO samples are listed in Table 1.

### Table 1. The values of band gap ($E_g$), flat-band potential ($E_{fb}$ vs NHE) of TiO$_2$ and TiO$_2$/ZnO films and their photocatalytic efficiency in process of Cr (VI) to Cr(III) photoreduction

<table>
<thead>
<tr>
<th>Sample</th>
<th>$E_{fb}$ vs NHE</th>
<th>Photocatalytic efficiency $k$, sec$^{-1}$</th>
</tr>
</thead>
<tbody>
<tr>
<td>TiO$_2$</td>
<td>-0.51</td>
<td>$2.2 \times 10^4$</td>
</tr>
<tr>
<td>TiO$_2$/ZnO (1%)</td>
<td>-1.21</td>
<td>$3.0 \times 10^4$</td>
</tr>
<tr>
<td>TiO$_2$/ZnO (5%)</td>
<td>-1.1</td>
<td>$2.9 \times 10^4$</td>
</tr>
<tr>
<td>TiO$_2$/ZnO (10%)</td>
<td>-1.0</td>
<td>$2.5 \times 10^4$</td>
</tr>
</tbody>
</table>

Photocatalytic activity of TiO$_2$ and TiO$_2$/ZnO films has been tested in the photoreduction of toxic Cr(VI) to non-toxic Cr(III) ions in acid water solutions in the presence of environmentally important substrate EDTA (Table 1). This process has been taken as a model of real wastewaters where oxidizing and reducing agents are present together for comparable studies of commercial samples and platinized TiO$_2$ powders[32]. The mechanism of photocatalytic Cr (VI) reduction in the presence of electron donors (EDTA, salicylic acid or other organic molecules) is well described herein[33]. Under irradiation in the presence of TiO$_2$/ZnO films, the changes in Cr(VI) concentration was followed by the decrease of absorption band intensity at 349 nm, simultaneously the absorption at 550 nm increased due to non-toxic Cr(III) formation (Fig.4.)

Efficiency of toxic Cr(VI) ions photoreduction grows in correlation with the flat-band potential shift to more negative values (from $-0.51$ V for TiO$_2$ to $-1.1$ V vs NHE for TiO$_2$/ZnO 1% samples). Doping of TiO$_2$ by 1-5% of Zn$^{2+}$ ions leads to increase the reaction rate constant from 0.22 to $3.0\times10^4$ c$^{-1}$, however the grow of Zn$^{2+}$ content from 1 to 10% causes to the diminishing of films photoactivity. Improvement of efficiency of TiO$_2$/ZnO samples with low Zn$^{2+}$ content as compared to pure TiO$_2$ films can be explained by the formation of new acid centres on the surface of mixed oxides[1-3, 21] and increase of lifetime of photogenerated electron-hole pair ($e^-$ and $h^+$) due to the appearance of new crystalline phase ZnO or Zn$_3$Ti$_2$O$_6$[6,7, 20-22]. Drop of catalytic efficiency for 10%ZnO/TiO$_2$ films can be connected with the low active ZnTiO$_3$ phase formation[7, 21].

### 3.3. Phase Composition and Electronic Structure of TiO$_2$/ZrO$_2$ Films

The adsorption-desorption isotherms of hexane on 773K calcined TiO$_2$ and ZrO$_2$/TiO$_2$ samples[15] demonstrated the type IV shape which indicated the presence of mesoporosity.
in accordance with[27]. The specific surface areas (S\textsubscript{BET}) and mean pore sizes of ZrO\textsubscript{2}/TiO\textsubscript{2} films annealed at 773K are listed in Table 2. Uniform porosity with r= 8-10 nm typical for samples with low ZrO\textsubscript{2} content. Pure TiO\textsubscript{2} and 30\% TiO\textsubscript{2}/ZrO\textsubscript{2} films show broader pore size distribution shifted to the larger pores with radius around 14 nm.

<table>
<thead>
<tr>
<th>Sample characteristics</th>
<th>S\textsubscript{BET}, m\textsuperscript{2}/g</th>
<th>Pore radii, nm</th>
</tr>
</thead>
<tbody>
<tr>
<td>TiO\textsubscript{2} porous*</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td>TiO\textsubscript{2}</td>
<td>816</td>
<td>3.8; 6.1; 13.8</td>
</tr>
<tr>
<td>TiO\textsubscript{2}/ZrO\textsubscript{2} (5% ZrO\textsubscript{2})</td>
<td>1007</td>
<td>8.2</td>
</tr>
<tr>
<td>TiO\textsubscript{2}/ZrO\textsubscript{2} (10% ZrO\textsubscript{2})</td>
<td>557</td>
<td>3.8; 9.7</td>
</tr>
<tr>
<td>TiO\textsubscript{2}/ZrO\textsubscript{2} (30% ZrO\textsubscript{2})</td>
<td>123</td>
<td>3.8; 14.2</td>
</tr>
</tbody>
</table>

*For film prepared without template, S\textsubscript{BET} cannot be measured directly

Figure 5. a). XRD patterns and b). XRD peaks of anatase crystal plane (101) of the powders after calcinations at 773K. TiO\textsubscript{2} (1) and TiO\textsubscript{2}/ZrO\textsubscript{2} (2 – 10, 3 – 30 mol.% of ZrO\textsubscript{2})

Only anatase phase (JCPDS-ICDD, \#21-1272) was identified in XRD patterns of TiO\textsubscript{2} and TiO\textsubscript{2}/ZrO\textsubscript{2} powders prepared from the precursors. XRD measurements of TiO\textsubscript{2}/ZrO\textsubscript{2} powders in the range of ZrO\textsubscript{2} concentrations 5-30 mol.% did not reveal any peaks, typical for crystalline zirconia phase. Whereas TiO\textsubscript{2} and TiO\textsubscript{2}/ZrO\textsubscript{2} (5-10\% ZrO\textsubscript{2}) powders show high crystallinity (80-70\%) with 9-11 nm anatase nanoparticles, TiO\textsubscript{2}/ZrO\textsubscript{2} (30\%) powder was amorphous after calcination at 673K. The increase of the calcination temperature up to 773K led to the insignificant grows of crystallinity for TiO\textsubscript{2}/ZrO\textsubscript{2} samples with low zirconium content.

Powder with 30 mol. \% of ZrO\textsubscript{2} after treatment at 500°C showed only weak reflex at 2\theta = 25.4 characteristic for TiO\textsubscript{2} anatase on the amorphous matrix background.

These results indicate that in the TiO\textsubscript{2}/ZrO\textsubscript{2} binary oxides, crystallization of titanium oxide is suppressed when Zr content increases due to the zirconia retarding effect on anatase crystallites’ growth[34]. Detailed analysis of XRD spectra of the TiO\textsubscript{2}/ZrO\textsubscript{2} powders proved the formation of solid solution Ti\textsubscript{1-x}Zr\textsubscript{x}O\textsubscript{2} with anatase structure as resulted from the anatase (101) crystal plane reflection shift into lower 2\theta region (fig. 3b) due to the differences in the ionic radii of Zr\textsuperscript{4+} and Ti\textsuperscript{4+}. The increase of lattice parameters and cell volume of solid solutions Ti\textsubscript{1-x}Zr\textsubscript{x}O\textsubscript{2} as function of zirconium content (x) was observed [37, 38, 16].

The application of Raman spectroscopy considerably expands the possibilities of study of the material structure, the phase transformation peculiarities, the quantum size effect, compositional effects, the material evolution with sintering and treatment. The group-theoretical analysis gives the existence of 15 optical modes in the centre of Brillouin zone of anatase TiO\textsubscript{2}: \Gamma \textsubscript{obs}=A\textsubscript{1g}+A\textsubscript{2u}+B\textsubscript{1g}+B\textsubscript{2u}+3E\textsubscript{g}+2E\textsubscript{u}. Among these modes, A\textsubscript{1g}, B\textsubscript{1g} and 3E\textsubscript{g} are Raman active, and modes A\textsubscript{2u}, B\textsubscript{2u}, 2E\textsubscript{u} are infrared active.

Raman spectra of TiO\textsubscript{2} and TiO\textsubscript{2}/ZrO\textsubscript{2} nanocrystals with different concentration of ZrO\textsubscript{2} heat treated at 773K were analyzed in[35]. The number and frequencies of the Raman bands for TiO\textsubscript{2} coincide with obtained in previous studies for anatase powder and single crystal[36]. The Raman bands at 148, 401, 522 and 648 cm\textsuperscript{-1} can be assigned as the E\textsubscript{g}, B\textsubscript{1g}, A\textsubscript{1g} or B\textsubscript{1g} and E\textsubscript{g} modes of anatase phase, respectively. No other bands characteristic for other polymorphs were found. As ZrO\textsubscript{2} concentration increases, the bands became broader; some of them are shifted (148, 401 cm\textsuperscript{-1}). Raman spectrum for TiO\textsubscript{2}/ZrO\textsubscript{2} (30\%) sample changes dramatically: the intensity decreases while the width at half maximum of the bands increases, and some new bands appear (Fig. 6a).

The spectrum of sol-gel derived ZrO\textsubscript{2}, which can be described as a mixture of amorphous zirconia and \(t\)-ZrO\textsubscript{2} is presented as reference.

Raman spectra of the TiO\textsubscript{2} and TiO\textsubscript{2}/ZrO\textsubscript{2} 5\% films annealed at 773K (4 layers) are shown in the fig. 7. The Raman bands at 141, 396, 454, 520, 593 and 632 cm\textsuperscript{-1} have been detected. In general, Raman spectra of the films are similar to the spectra of corresponding powders, but all bands broaden and shift towards higher or lower wavenumbers depending on the type of vibration. Formation of the crystalline structure for the TiO\textsubscript{2}/ZrO\textsubscript{2} mesoporous films with zirconia concentration 10-30 mol.% was not registered, most probably due to their amorphous character that coincides well with our results of AFM and XRD mentioned above.
The electronic structure of nanosized zirconia-doped titanium dioxide films (5–30 mol% ZrO₂) has been investigated by means of XPS. The main contribution to the Ti2p-line of all samples has the component with the binding energy Ti2p3/2 = 458.5 eV. With increasing doping, the contribution of the component of E_b Ti2p3/2 = 458.9 eV grows. Within this range of energies, structurally nonequivalent TiO₂ phases are usually observed [29] The correlation between the relative contribution of the component with E_b Ti2p3/2 = 458.9 eV to Ti2p-spectra and the relative content of the doping element in the films (Table 3) can indicate the formation of the ZrTiO₄ phase [29] or the solid solution T𝑖₁₋ₓZrₓO₂ [37, 38].

The components with E_b Zr3d5/2 = 181.6 eV and E_b Zr3d5/2 = 182.3 eV in Zr3d-spectra of ZrO₂ and TiO₂/ZrO₂ films can be correlated with nonequivalent zirconium atoms of the Ti-O-Zr bonds (phase 1 and phase 2 respectively) [29, 39]. The contribution of phase 1 (E_b = 181.6 eV) into Zr3d-spectrum diminishes with increase of dopant content, the contribution of the phase 2 (E_b = 182.3 eV) is maximal for the sample TiO₂/ZrO₂ (30 mol.%). A decrease in the contribution of the component with E_b Zr3d5/2 = 181.6 eV can be caused by the absorption effects due to the localization of the phase 2 on the surface of microcrystallites of the phase 1. Taking into account the results of deconvolution of the Ti2p-spectra, the signal in the range of E_b Zr3d5/2 = 181.6 eV can be related to the formation of ZrTiO₄ phase [29] or T𝑖₁₋ₓZrₓO₂ (solid solution of Zr in TiO₂) [37] that is more probable, as XRD and Raman spectra analysis of corresponding powders after calcinations at 500°C showed the presence of only one crystalline phase – anatase with slightly distorted lattice parameters.

Thus, XPS investigation showed that formation of the photocatalytically active phase T𝑖₁₋ₓZrₓO₂ takes place when template assisted sol-gel method of synthesis of zirconium-doped TiO₂ mesoporous films is used for a dopant loading up to 10%. This phase is characterized by increased surface area at high crystallinity degree, with maximum quantity of hydroxyl groups for the sample TiO₂/ZrO₂ (10 mol.%) (Table 3), probably indicating an increase of the quantity of the surface active sites on the surface unit. Thus, XPS investigation showed that formation of the photocatalytically active phase T𝑖₁₋ₓZrₓO₂ takes place when template assisted sol-gel method of synthesis of zirconium-doped TiO₂ mesoporous films is used for a dopant loading up to 10%. This phase is characterized by increased surface area at high crystallinity degree, with maximum quantity of hydroxyl groups for the sample TiO₂/ZrO₂ (10 mol.%). With increasing Zr concentration up to 30%, formation of amorphous ZrO₂ phase begins which is accompanied by a sharp decrease of surface area of the films and number of surface hydroxyl groups that will have pronounced influence on the photocatalytical activity of the films.
3.4. Photocatalytic Properties of TiO₂/ZrO₂ Films

Spectral dependences of photocurrent were measured for the TiO₂/ZrO₂ electrodes (TiO₂/ZrO₂ films were coated on Ti substrate) to obtain the value of the band gap energy.

For the tested TiO₂/ZrO₂ compositions, linear dependence in \( (\nu \cdot h)^{1/2} = f(h\nu) \) coordinates was not obtained due to some reasons such as: photocurrent in the long-wave spectral region caused by defects in the anatase structure and/or low intensity of photocurrent corresponded to indirect transition in thin films due to low absorption coefficient.

The obtained experimental data fit better to a direct transition[40]. Band gap (E_g) values were calculated by the direct electrochemical measurements, linear dependence of photocurrent as a function of applied potential in aqueous 0.5 M NaCl plotted against applied potential by extrapolation straight line of these dependences to the abscissa. Flatband potentials were estimated from \( \frac{i_{ph}}{\eta} \) for TiO₂/ZrO₂ films coated on Ti substrate in 0.5 M NaCl. Flatband potentials were estimated from \( \frac{i_{ph}}{\eta} \) for TiO₂/ZrO₂ films coated on Ti substrate in 0.5 M NaCl. Using the empirical construction \( E_{fb} = \frac{-\varepsilon F}{\varepsilon + \varepsilon_{S}} \), where \( \varepsilon \) is the dielectric constant of the semiconductor, \( \varepsilon_{S} \) is the dielectric constant of the substrate, and \( \varepsilon_{fb} \) is the flatband potential.

The position of the flatband potential (E_fb) of the catalyst was determined by the direct electrochemical measurements of photocurrent as a function of applied potential in aqueous 0.5 M NaCl. Flatband potentials were estimated from \( \frac{i_{ph}}{\eta} \) changes measured at the photocurrent maximum for TiO₂ and TiO₂/ZrO₂ films coated on the titanium substrate in aqueous 0.5 M NaCl plotted against applied potential by extrapolation straight line of these dependences to the abscissa. Flatband potential values for the samples with different zirconium content differ insignificantly and are comparable with the value of \(-0.47\) - \(-0.49\) V obtained at pH \( \approx 7 \) for nitrogen-doped titanium dioxide[42] and \( U_{fb} = -0.58 \) V measured for anatase single crystal[43, 44].

Photocatalytic activity of mesoporous TiO₂ and TiO₂/ZrO₂ (5-30%) films, in comparison with films prepared without template, increases in accordance with increasing specific surface area of the samples. The conversion of Cr₂O₇⁻², calculated for mesoporous TiO₂ films, was 4 times higher, than that observed for nonporous samples and 10 times higher, than it was reported in[45] for the equal amount of TiO₂, supported on hollow glass microbeads during the same time of irradiation.

The enhanced activity was observed for TiO₂/ZrO₂ films with low concentration of zirconium that possessed the high surf area and composed from nanoparticles with mean size 3-4 nm. Zr doping retards not only anatase to rutile transformation, but also inhibits the crystalline growth[1-3, 34]. It can be seen that in general there is the increase of E_g with the anodic shift of the upper edge of the valence band positions as the Zr concentration increases. Processes of EDTA oxidation accelerate, improving charge separation, and Cr (IV) reduction proceeds faster due to synergism between the oxidation and reduction reactions. Further increasing of Zr content leads to low crystallinity of 30%ZrO₂/TiO₂ and amorphous structure of 50%ZrO₂/TiO₂ samples. This effect explains the drop of activity of these samples.

3.5. Phase Composition and Electronic Structure of TiO₂/ZrO₂/SiO₂ Films

Ternary TiO₂/ZrO₂/SiO₂ films were synthesized via sol-gel method without template addition to obtain photocatalytic mechanically strength coatings with high thermal, chemical and radiation stability. As was reported previously[24] prepared transparent nanosized ternary films had good optical quality (refractive index 1.82), remained stable and retained the high photocatalytic activity after \( \beta \)-irradiation as well as contact with aggressive chemical environment.

XRD analysis of ternary systems did not give clear information about crystalline structure of the composites. This is more likely due to the insufficient resolution of XRD method used for investigation of the nanosized systems than due to the formation of amorphous oxide network. In the XRD spectra of pure TiO₂ and ZrO₂ films deposited onto glass substrates and heat treated at 600°C can be distinguished reflections corresponding to the TiO₂ anatase and tetragonal ZrO₂ phases. As it was discussed previously[12] common crystallization in the binary or ternary systems during oxide network formation causes inhibitory influence on the growth and agglomeration of the individual phases of the components, partly even due to the chemical interaction between components with formation of Ti-O-Si, Ti-O-Zr and Si-O-Zr bonds. Vogel et al[12] also reported formation of tiny crystallites of TiO₂ after calcination even at 623K. These titanium dioxide crystallites embedded into amorphaous
oxide network were “amorphous for XRD” and detected by electron diffraction and bright field TEM.

Diffraction patterns of TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} powders prepared via gelation of the films precursors, their drying in air with following heat treatment at 873K, 973K and 1073K presented on Fig. 8. XRD analysis evidenced simultaneous crystallization of two crystalline phases – anatase and srilankite Ti\textsubscript{2}ZrO\textsubscript{6}[46-48].

![Figure 8](image_url)  
**Figure 8.** (a) X-ray diffraction patterns of TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} powders calcined at: 873K - 1; 973K - 2; 1073K – 3; a – anatase, * - srilankite; (b) Raman spectra of TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} powder calcined at 1073K.

The Raman spectrum of TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} powder (Fig.8, b) thermal treated at 800°C depicts a set of reflexes related to anatase (lines at 146, 400, 525, 640 cm\textsuperscript{-1})[49, 50] and only one weaker reflex at 719 cm\textsuperscript{-1}, corresponding to ZrO\textsubscript{2}[51].

Formation of chemical bonds between components in binary and ternary oxide mixtures was investigated using XPS method. For this purpose detailed spectra of binary and ternary sol-gel films and pure oxides were investigated and compared[23].

In sample 1 oxygen O 1s and silicon Si 2p peaks positions (532.9 eV and 103.44 eV respectively) coincide with known[52] peak positions in SiO\textsubscript{2}: O 1s peak - 532.89 eV and Si 2p peak - 103.6 eV. The shift of Si 2p peak is 0.51 eV in sample 2 and 1.03 eV in sample 4 then Ti atomic concentration changes from 0% to 20% and 36%, respectively. Such peak position shift suggests its uniform dependence on the Ti concentration. Ti 2p\textsubscript{3/2} and Zr 3d\textsubscript{5/2} peak positions (Fig. 10) for mixed oxides are shifted towards higher binding energies (positive shift) comparing to the peak position in sample of sol-gel prepared pure TiO\textsubscript{2} or ZrO\textsubscript{2} film.

Similar shift behaviors can be noticed for Si 2p – Ti 2p and Si 2p – Zr 3d peaks, therefore these shifts can be attributed to the formation of binary and ternary oxides with Si – O – Ti, Si – O – Zr, Ti – O – Zr, Si – O – Ti – O – Zr bonds.

Described above peaks shifts are in good agreement with the red shift of optical absorption for single and mixed oxides and \( E_g \) reduction from 8.9 eV for SiO\textsubscript{2} to 3.68 eV for TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} (49:21:30) film. It can be also mentioned that Si 2p and O 1s peaks position shift dependence correlates well with the photocatalytic activity of ternary TiO\textsubscript{2}/ZrO\textsubscript{2}/SiO\textsubscript{2} films in the process of Cr(VI) ions
4. Conclusions

Sol-gel synthesis of nanostructured mixed oxide films (mesoporous TiO$_2$/ZnO and TiO$_2$/ZrO$_2$, nonporous SiO$_2$/TiO$_2$/ZrO$_2$) using metal alkoxides as precursors and acetylacetone as a complexing agent assures extensive bridging of components through the oxygen, which has pronounced influence on phase composition, electronic structure, photoelectrochemical characteristics and photocatalytic activity of obtained coatings.

In the case of TiO$_2$/ZnO nanocomposites, the crystallinity of the TiO$_2$/ZnO films slightly increased with Zn content and ZnTiO$_3$ perovskite phase is formed. The films with low Zn content (1-5%) showed superhydrophilicity. Direct photoelectrochemical investigation of the mesoporous TiO$_2$/ZnO films showed the cathodic shift of the flat band potential position and the increase of the photocurrent quantum yield in comparison with unmodified TiO$_2$ electrodes that coincided with the increase of their activity in the process of Cr(VI) photoreduction.

Zirconium incorporation into TiO$_2$ lattice with formation of Ti$_{1-x}$Zr$_x$O$_2$ solid solution containing anatase structure leads to increase of $E_g$ with the anodic shift of the upper edge of the valence band position accelerating photocatalytic processes due to the improvement of charge separation. The maximum content of OH-groups is observed for the sample TiO$_2$/ZrO$_2$ (10 mol.% ZrO$_2$) indicating an increase of the quantity of the surface active sites.

Under experimental conditions of sol-gel procedure of ternary systems formation, two crystalline phases are formed anatase and srilankite (Ti$_2$ZrO$_6$). Analysis of the XPS spectra showed the formation of Si – O – Ti, Si – O – Zr, Ti – O – Zr, Si – O – Ti – O – Zr bonds. Oxygen and silicon peak positions evolution detected by XPS correlate with $E_g$ reduction of analyzed mixed oxides that resulted in the substantial increase of photocatalytic activity in the process of Cr (VI) ions photoreduction.

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